Vishay Semiconductors

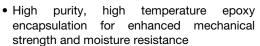
High Performance Schottky Rectifier, 2 x 15 A



PRIMARY CHARACTERISTICS							
I _{F(AV)}	2 x 15 A						
V_{R}	35 V, 45 V						
V _F at I _F	See Electrical table						
I _{RM} max.	40 mA at 125 °C						
T _J max.	150 °C						
E _{AS}	16 mJ						
Package	3L TO-220AB						
Circuit configuration	Common cathode						

FEATURES

- 150 °C T_{.I} operation
- Low forward voltage drop
- High frequency operation





- Guard ring for enhanced ruggedness and long term reliability
- Designed and qualified according to JEDEC®-JESD 47
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION

This center tap Schottky rectifier has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS								
SYMBOL	CHARACTERISTICS	VALUES	UNITS					
I _{F(AV)}	Rectangular waveform (per device)	30	Α					
V _{RRM}		35/45	V					
I _{FRM}	T _C = 130 °C (per leg)	30	^					
I _{FSM}	t _p = 5 μs sine	1060	А					
V _F	30 A _{pk} , T _J = 125 °C	0.73	V					
T _J	Range	-65 to +150	°C					

VOLTAGE RATINGS									
PARAMETER SYMBOL VS-MBR2535CT-M3 VS-MBR2545CT-M3 UNIT									
Maximum DC reverse voltage	V_{R}	35	45	W					
Maximum working peak reverse voltage	V_{RWM}	35	45	V					

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST CO	VALUES	UNITS				
Maximum average forward per leg		T 130 °C rated V-		15				
current per device	I _{F(AV)}	$T_C = 130 ^{\circ}\text{C}$, rated V_R		30				
Peak repetitive forward current per leg	I _{FRM}	Rated V _R , square wave, 20 kHz, T _C = 130 °C		30				
Non-repetitive peak surge current	I _{ESM}	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated V _{RRM} applied	1060 A				
	TOW	Surge applied at rated load conditions halfwave, single phase, 60 Hz		150				
Non-repetitive avalanche energy per leg	E _{AS}	$T_{J} = 25 ^{\circ}\text{C}, I_{AS} = 2 \text{A}, L = 8 \text{mH}$		16	mJ			
Repetitive avalanche current per leg	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		2	Α			



Vishay Semiconductors

ELECTRICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST COND	VALUES	UNITS			
Maximum forward valtage drep	V (1)	30 A	T _J = 25 °C	0.82			
Maximum forward voltage drop	V _{FM} ⁽¹⁾	30 A	T _J = 125 °C	0.73	V		
Maximum instantaneous reverse current	I _{RM} ⁽¹⁾	T _J = 25 °C	Rated DC voltage	0.2	mΛ		
Maximum instantaneous reverse current	'RM (*)	T _J = 125 °C	Haled DC vollage	40	mA		
Threshold voltage	V _{F(TO)}	$T_{.l} = T_{.l}$ maximum		0.355	V		
Forward slope resistance	r _t	ıj = ıjınaxımum		12.3	m $Ω$		
Maximum junction capacitance	C _T	V _R = 5 V _{DC} (test signal range	700	pF			
Typical series inductance	L _S	Measured from top of termina	8.0	nH			
Maximum voltage rate of change	dV/dt	Rated V _R	10 000	V/µs			

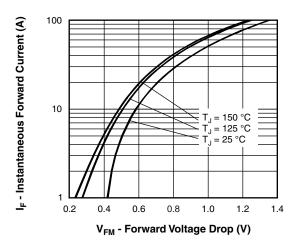
Note

 $^{^{(1)}\,}$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction temperatur	e range	T_J		-65 to +150	°C			
Maximum storage temperature	e range	T _{Stg}		-65 to +175				
Maximum thermal resistance, junction to case per leg		R _{thJC}	DC operation	1.5	°C/W			
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.50	G/ VV			
Approximate weight				2	g			
Approximate weight				0.07	OZ.			
Mounting torque	Ma unting the results		Non-lubricated threads	6 (5)	kgf · cm			
woulding torque	maximum		Non-iubricated tirreads	12 (10)	(lbf · in)			
Marking device			Casa style 2L TO 220AB	MBR25350				
			Case style 3L TO-220AB	MBR2545CT				



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100 T_{.1} = 150 °C I_R - Reverse Current (mA) 10 0.1 0.01 0.001 0.0001 25 30 10 15 20 40 45 0 V_R - Reverse Voltage (V)

Fig. 1 - Maximum Forward Voltage Drop Characteristics (Per Leg)

Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage (Per Leg)

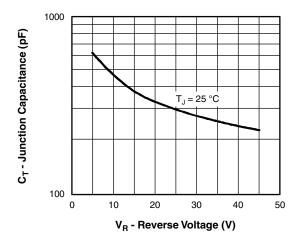


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

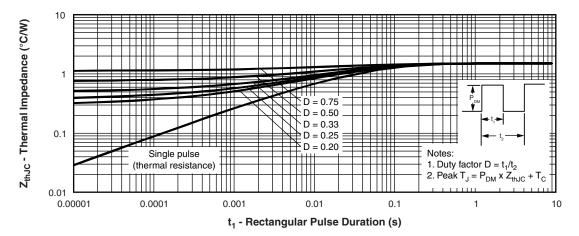


Fig. 4 - Maximum Thermal Impedance ZthJC Characteristics (Per Leg)

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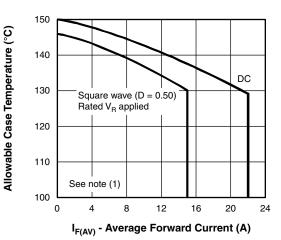


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current (Per Leg)

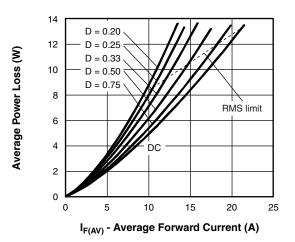


Fig. 6 - Forward Power Loss Characteristics (Per Leg)

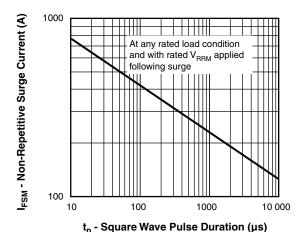


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

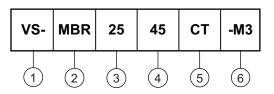
Note

(2) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{th,JC}$; $Pd = forward power loss = I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6); $Pd_{REV} = inverse power loss = V_{R1} \times I_R$ (1 - D); I_R at $V_{R1} = rated V_R$

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ORDERING INFORMATION TABLE

Device code



Vishay Semiconductors product

2 - Schottky MBR series

3 - Current rating (30 A)

35 = 35 V 45 = 45 V

5 - CT = essential part number

Environmental digit
-M3 = halogen-free, RoHS-compliant, and termination lead (Pb)-free

ORDERING INFORMATION (Example)								
PREFERRED P/N BASE QUANTITY PACKAGING DESCRIPTION								
VS-MBR2535CT-M3	50	Antistatic plastic tubes						
VS-MBR2545CT-M3	50	Antistatic plastic tubes						

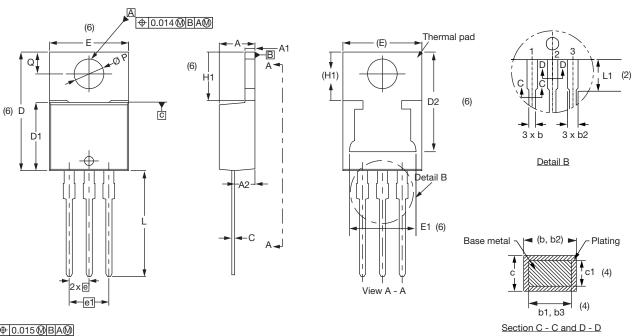
LINKS TO RELATED DOCUMENTS							
Dimensions <u>www.vishay.com/doc?96154</u>							
Part marking information	www.vishay.com/doc?95028						



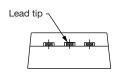
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3L TO-220AB

DIMENSIONS in millimeters and inches



⊕ 0.015 **M** B A **M**



Conforms to JEDEC® outline TO-220AB

SYMBOL	MILLIMETERS		INC	HES	NOTES	SYMBOL	MILLIN	IETERS	INC	HES	NOTES	
STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES	NOTES	STWIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.25	4.65	0.167	0.183			D2	11.68	13.30	0.460	0.524	6, 7
A1	1.14	1.40	0.045	0.055			E	10.11	10.51	0.398	0.414	3, 6
A2	2.50	2.92	0.098	0.115			E1	6.86	8.89	0.270	0.350	6
b	0.69	1.01	0.027	0.040			е	2.41	2.67	0.095	0.105	
b1	0.38	0.97	0.015	0.038	4		e1	4.88	5.28	0.192	0.208	
b2	1.20	1.73	0.047	0.068			H1	6.09	6.48	0.240	0.255	6
b3	1.14	1.73	0.045	0.068	4		L	13.52	14.02	0.532	0.552	
С	0.36	0.61	0.014	0.024			L1	3.32	3.82	0.131	0.150	2
c1	0.36	0.56	0.014	0.022	4		ØΡ	3.54	3.91	0.139	0.154	
D	14.85	15.35	0.585	0.604	3		Q	2.60	3.00	0.102	0.118	
D1	8.38	9.02	0.330	0.355		1		•			•	

Notes

- ⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3, and c1 apply to base metal only
- Controlling dimensions: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2, and E1
- (7) Outline conforms to JEDEC® TO-220, except D2



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